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Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



MOSFETs Silicon N-Channel MOS (π-MOSVII)

# TK7A90E

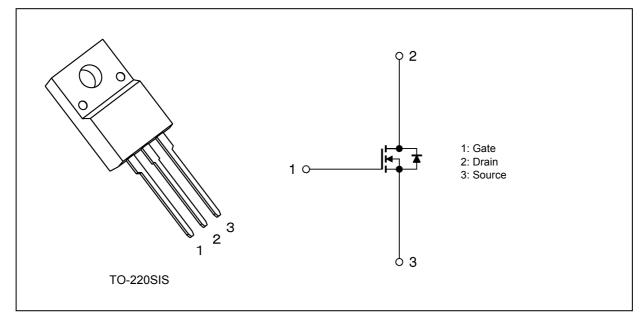
### 1. Applications

Switching Voltage Regulators

#### 2. Features

- (1) Low drain-source on-resistance:  $R_{DS(ON)} = 1.6 \Omega$  (typ.)
- (2) Low leakage current :  $I_{\rm DSS}$  = 10  $\mu A$  (max)  $(V_{\rm DS}$  = 720 V)
- (3) Enhancement mode:  $V_{th}$  = 2.5 to 4.0 V ( $V_{DS}$  = 10 V,  $I_D$  = 0.7 mA)

#### 3. Packaging and Internal Circuit



### 4. Absolute Maximum Ratings (Note) (T<sub>a</sub> = 25 °C unless otherwise specified)

Characteristics			Rating	Unit
Drain-source voltage		V <sub>DSS</sub>	900	V
Gate-source voltage		V <sub>GSS</sub>	±30	7
Drain current (DC)	(Note 1)	Ι <sub>D</sub>	7	Α
Drain current (pulsed)	(Note 1)	I <sub>DP</sub>	21	7
Power dissipation (T	「 <sub>c</sub> = 25°C)	PD	45	W
Single-pulse avalanche energy	(Note 2)	E <sub>AS</sub>	235	mJ
Avalanche current	·	I <sub>AR</sub>	7	Α
Reverse drain current (DC)	(Note 1)	I <sub>DR</sub>	7	
Reverse drain current (pulsed)	(Note 1)	I <sub>DRP</sub>	21	]
Channel temperature	·	T <sub>ch</sub>	150	°C
Storage temperature		T <sub>stg</sub>	-55 to 150	7
Isolation voltage (RMS)		V <sub>ISO(RMS)</sub>	2000	V
Mounting torque		TOR	0.6	N · m

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### 5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance		2.78	°C/W
Channel-to-ambient thermal resistance		62.5	

Note 1: Ensure that the channel temperature does not exceed 150 °C.

Note 2: V\_DD = 90 V, T\_ch = 25°C (initial), L = 8.8 mH, R\_G = 25  $\Omega,$  I\_AR = 7 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

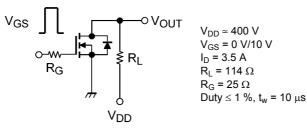
#### 6. Electrical Characteristics

### 6.1. Static Characteristics (Ta = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I <sub>GSS</sub>	$V_{GS}$ = ±30 V, $V_{DS}$ = 0 V	_	_	±1	μA
Drain cut-off current	I <sub>DSS</sub>	V <sub>DS</sub> = 720 V, V <sub>GS</sub> = 0 V	_	_	10	
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	900	_	_	V
Gate threshold voltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.7 mA	2.5	_	4.0	
Drain-source on-resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 3.5 A	_	1.6	2.0	Ω

### 6.2. Dynamic Characteristics (Ta = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C <sub>iss</sub>	$V_{DS}$ = 25 V, $V_{GS}$ = 0 V, f = 1 MHz	_	1350	_	pF
Reverse transfer capacitance	C <sub>rss</sub>		_	10	_	
Output capacitance	C <sub>oss</sub>		_	110	_	
Gate resistance	r <sub>g</sub>	V <sub>DS</sub> = OPEN, f = 1 MHz	_	4.0	—	Ω
Switching time (rise time)	t <sub>r</sub>	See Fig. 6.2.1.	_	20	_	ns
Switching time (turn-on time)	t <sub>on</sub>		_	55	_	
Switching time (fall time)	t <sub>f</sub>		_	15	_	
Switching time (turn-off time)	t <sub>off</sub>		_	85	_	
MOSFET dv/dt ruggedness	dv/dt	$V_{DD}$ = 0 to 400 V, I <sub>D</sub> = 7 A	20	_	_	V/ns



#### Fig. 6.2.1 Switching Time Test Circuit

### 6.3. Gate Charge Characteristics ( $T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx 400 \text{ V}, \text{ V}_{GS}$ = 10 V, I <sub>D</sub> = 7 A	_	32	—	nC
Gate-source charge 1	Q <sub>gs1</sub>		_	10	_	
Gate-drain charge	Q <sub>gd</sub>			12	_	

#### 6.4. Source-Drain Characteristics (T<sub>a</sub> = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage	V <sub>DSF</sub>	I <sub>DR</sub> = 7 A, V <sub>GS</sub> = 0 V	_	—	-1.7	V
Reverse recovery time		I <sub>DR</sub> = 7 A, V <sub>GS</sub> = 0 V	_	1100	—	ns
Reverse recovery charge	Q <sub>rr</sub>	_dI <sub>DR</sub> /dt = 100 A/μs	_	8	_	μC
Peak reverse recovery current	I <sub>rr</sub>		_	18	_	A

### 7. Marking (Note)

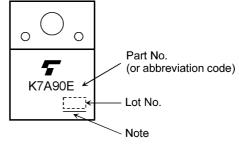
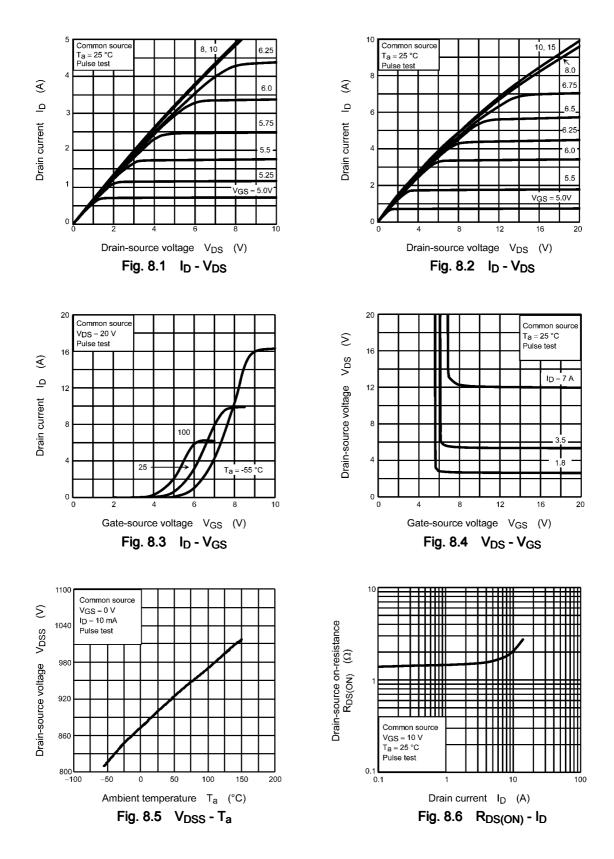


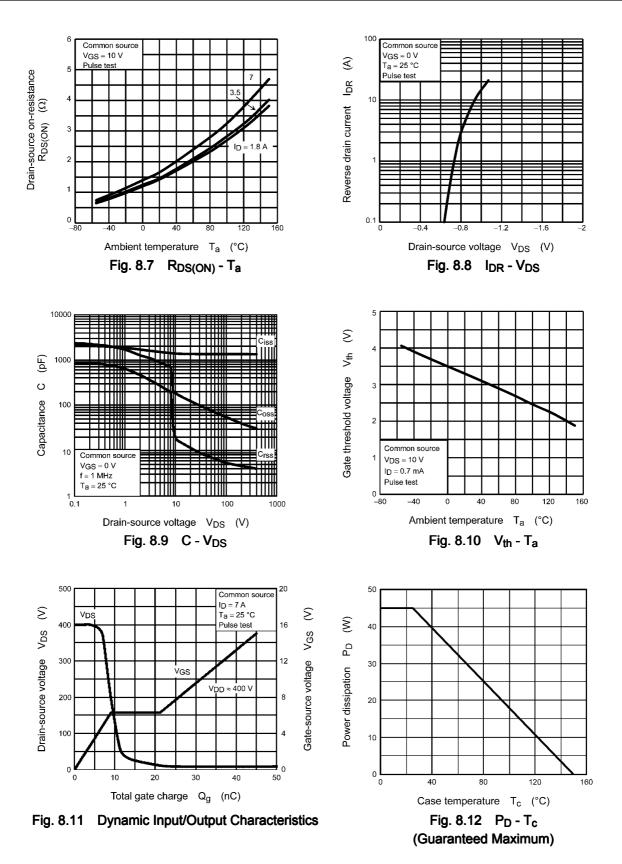
Fig. 7.1 Marking

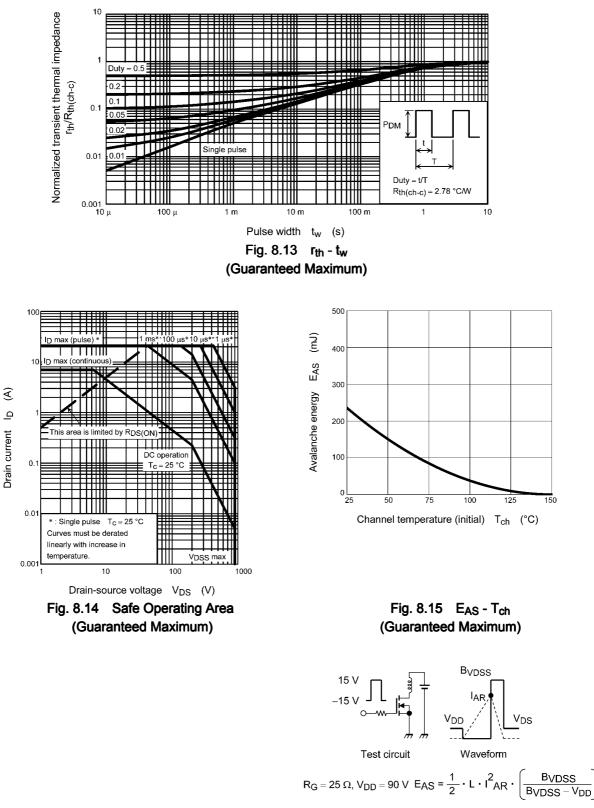
Note: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]] Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

### 8. Characteristics Curves (Note)







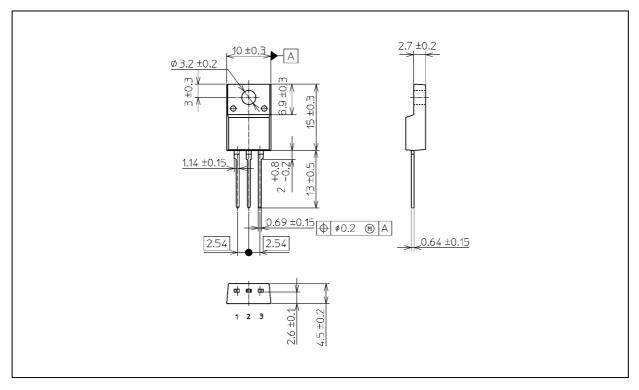


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

### TK7A90E

### Package Dimensions

Unit: mm



#### Weight: 1.7 g (typ.)

Package Name(s)			
JEITA: SC-67			
TOSHIBA: 2-10U1S			
Nickname: TO-220SIS			

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